Sheet 1 of 1

Form PTO-1449 U.S. DEPARTMENT OF COMMERCE ATTY. DOCKET NO. SERIAL NO. 026827/0154 (MODIFIED) 09/658,023 PATENT AND TRADEMARK OFFICE **APPLICANT** INFORMATION DISCHOSURE CITATION Boris KOBRIN, et al. **FILING DATE GROUP ART UNIT** FEB 2 0 2001 September 8, 2000 several sheet 🚮 necessary) 17581763 PADEMARY **U.S. PATENT DOCUMENTS FILING DATE** DOCUMENT **EXAMINER** SUB-CLASS DATE NAME REF IF INITIAL **CLASS NUMBER** APPROPRIATE 4.751,170 06/14/1988 Mimura et al. **A1** صياا **A2** 4,803,181 02/07/1989 Buchmann et al. 437 228 12/12/1989 Koshiba et al. 156 345 А3 4,886,565 **A4** 5,788,447 08/04/1998 Yonemitsu et al. 414 217 **A5** 5,863,705 01/26/1999 Sezi et al. 430 311 08/08/2000 Lin et al. 430 314 6,100,014 **A6** 6,110,637 08/29/2000 Sezi et al. 430 270.1 Α7 Duo C) 1 00 **FOREIGN PATENT DOCUMENTS** TRANSLATION SUB-**DOCUMENT CLASS** REF DATE **COUNTRY** NUMBER **CLASS** YES NO JP 4-14049 01/20/1992 Japan Abstract **A8** OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.) "Nanometer Sidewall Lithography By Resist Silylation", P. Vettiger, et al., J. Vac. Sci. Technol., Nov./Dec 1989. Α9 Dus Vol. 7, No. 6, pages 1756-1759 **EXAMINER DATE CONSIDERED** 13/02 EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include any copy of this form with next communication to applicant.

Page 1 of 2 Form PTO-1449 U.S. DEPARTMENT OF COMMERCE ATTY. DOCKET NO. SERIAL NO. (MODIFIED) PATENT AND TRADEMARK OFFICE 026827-0154 09/658,023 **APPLICANT** P E INFORMATION DISCLOSURE CITATION Boris KOBRIN et al. FILING DATE **GROUP ART UNIT** OCT 2 4 2001 (Uae several sheets if necessary) 09/08/2000 TIRN A TRADE **U.S. PATENT DOCUMENTS** DOCUMENT FILING DATE **EXAMINER** SUB-**CLASS** REF DATE NAME CLASS INITIAL NUMBER **APPROPRIATE** 430 **A1** 4,657,845 4/14/87 Frechet et al. 326 5,858,621 1/12/99 Yu et al. A2 430 12/22/98 Sezi et al. А3 5,851,733 4,377,437 3/22/83 Taylor et al. A4 2-1PE 6 4,377,734 3/22/83 Mashiko et al. **A5** 6/21/83 4,389,482 Bargon et al. A6 430 4,419,809 12/13/83 Riseman et al. A7 De La Moneda et al. 5/1/84 4,445,267 **8**A 029 Trumpp et al. 4,502,914 3/5/85 Α9 150 3/12/85 Meyer et al. 430 A10 4,504,574 331 11/12/85 Ito et al. 4,552,833 325 A11 U30 4,601,778 7/22/86 Robb 628 A12 56 9/23/86 Chiong et al. 4,613,398 A13 156 4,690,729 9/1/87 Douglas A14 156 5,599,745 2/4/97 Reinberg A15 5,792,593 8/11/98 McClure et al. A16 430 Andricacos et al. 361 A17 5,825,609 10/20/98 321.4 9/9/97 Robertson et al. 5,665,251 A18 216 027 4/20/99 Burns et al. 5,895,273 438 A19 11/9/82 Fu 4,358,340 A20 A21 4,209,349 6/24/80 Ho et al. 2/7/89 4,803,181 Buchmann et al. AUPO A22 228 437 **FOREIGN PATENT DOCUMENTS** TRANSLATION **DOCUMENT** SUB-DATE COUNTRY CLASS REF NUMBER CLASS YES NO

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